

HMC1133LP5E

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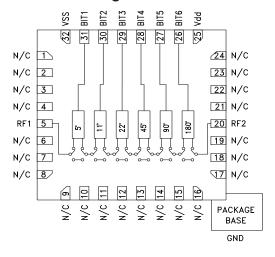
GaAs MMIC 6-BIT DIGITAL PHASE SHIFTER, 4.8 - 6.2 GHz

Typical Applications

The HMC1133LP5E is ideal for:

- EW Receivers
- Weather & Military Radar
- Satellite Communications
- Beamforming Modules
- Phase Cancellation

Functional Diagram



Features

Low RMS Phase Error: 2.8°
Low Insertion Loss: 5 dB
High Linearity: +46 dBm
Positive Control Logic

360° Coverage, LSB = 5.625°

32 Lead 5x5mm SMT Package: 25mm²

General Description

The HMC1133LP5E is a 6-bit digital phase shifter which is rated from 4.0 to 7 GHz, providing 360 degrees of phase coverage, with a LSB of 5.625 degrees. The HMC1133LP5E features very low RMS phase error of 2.8 degrees and extremely low insertion loss variation of ± 0.4 dB across all phase states. This high accuracy phase shifter is controlled with positive control logic of 0/+5V The HMC1133LP5E is housed in a compact 5x5 mm plastic leadless SMT package and is internally matched to 50 Ohms with no external components.

Electrical Specifications

 $T_A = +25^{\circ}$ C, Vss= -5V, Vdd= +5V, BIT1 to BIT6 = 0/ +5V, 50 Ohm System

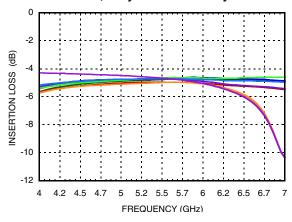
Parameter	Min.	Тур.	Max.	Units
Frequency Range	4.8		6.2	GHz
Insertion Loss*	3.5		6.8	dB
Input Return Loss*		13		dB
Output Return Loss*		15		dB
Phase Error*		±5.625	±10	deg
RMS Phase Error		2.8		deg
Amplitude Settling Time (50% cntl to +/- 0.1dB margin of final RFout)		125		nS
Phase Settling Time (50% cntl to +/-1 degree margin of final RFout)		100		nS
Insertion Loss Variation*		±0.4		dB
Input Power for 1 dB Compression		30		dBm
Input Third Order Intercept		46		dBm
Control Voltage Current		10		μΑ
Bias Control Current		13.5		mA

^{*}Note: Major States Shown

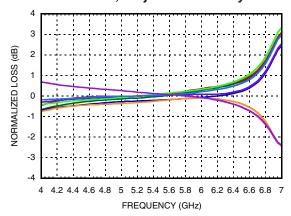


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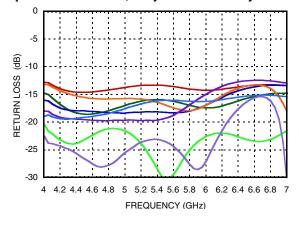
Insertion Loss, Major States Only



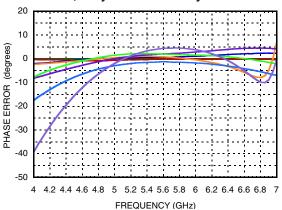
Normalized Loss, Major States Only



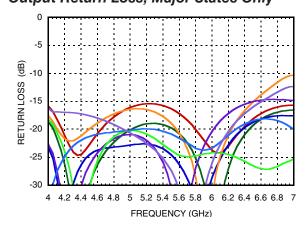
Input Return Loss, Major States Only



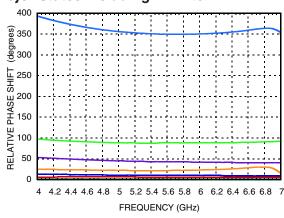
Phase Error, Major States Only



Output Return Loss, Major States Only



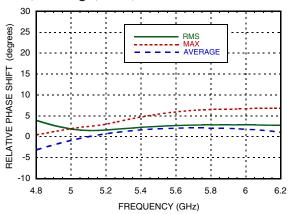
Relative Phase Shift Major States Including All Bits



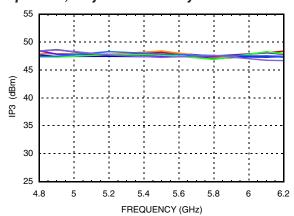


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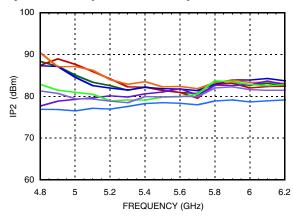
Relative Phase Shift, RMS, Average, Max, All States



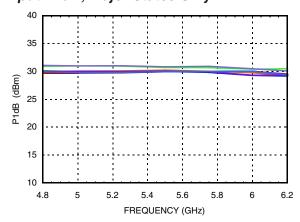
Input IP3, Major States Only



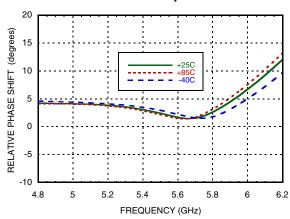
Input IP2, Major States Only



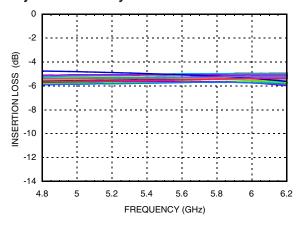
Input P1dB, Major States Only



RMS Phase Error vs. Temperature



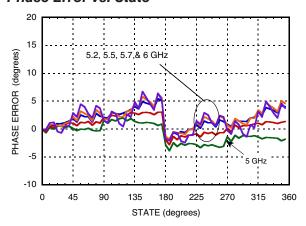
Insertion Loss vs. Temperature, Major States Only





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Phase Error vs. State



Bias Voltage & Current

Vdd	Idd
5.0	6mA
Vss	Iss
-5.0	7.5mA

Control Voltage

State	Bias Condition	
Low (0)	0 to 0.2 Vdc	
High (1)	Vdd ±0.2 Vdc @ 10 μA Typ.	

Absolute Maximum Ratings

Input Power (RFIN)	29 dBm (T= +85 °C)	
Bias Voltage Range (Vdd)	-0.2 to +7V	
Bias Voltage Range (Vss)	+0.2 to -7V	
Channel Temperature (Tc)	150 °C	
Thermal Resistance (channel to ground paddle)	109 °C/W	
Storage Temperature	-65 to +150 °C	
Operating Temperature	-40 to +85 °C	
ESD sensitivity (HBM)	Class1A (passed 250V)	



Truth Table

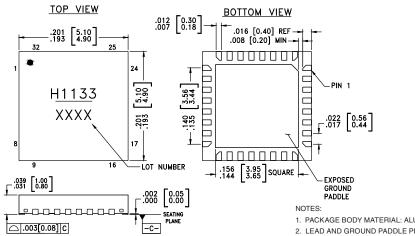
*Reference corresponds to monotonic setting

Control Voltage Input					Phase Shift (Degrees)		
Bit 1	Bit 2	Bit 3	Bit 4	Bit 5	Bit 6	RFIN - RFOUT	
0	0	0	0	0	0	Reference*	
1	0	0	0	0	0	5.625	
0	1	0	0	0	0	11.25	
0	0	1	0	0	0	22.5	
0	0	0	1	0	0	45.0	
0	0	0	0	1	0	90.0	
0	0	0	0	0	1	180.0	
1	1	1	1	1	1	354.375	
Any combination of the above states will provide a phase shift approximately equal to the sum of the bits selected.							



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Outline Drawing



- 1. PACKAGE BODY MATERIAL: ALUMINA
- 2. LEAD AND GROUND PADDLE PLATING: 30-80 MICROINCHES GOLD OVER 50 MICROINCHES MINIMUM NICKEL.
- 3. DIMENSIONS ARE IN INCHES [MILLIMETERS].
- 4. LEAD SPACING TOLERANCE IS NON-CUMULATIVE
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm DATUM -C-
- 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
- 7. CLASSIFIED AS MOISTURE SENSITIVITY LEVEL (MSL) 1.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [2]
HMC1133LP5E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL3 [1]	<u>H1133</u> XXXX

^[1] Max peak reflow temperature of 260 °C

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1 - 4, 6 - 19, 21 - 24	N/C	No connection required. These pins may be connected to RF/DC ground without affecting performance.	
5	RF1	This port is DC coupled and matched to 50 Ohms.	RF1 O
26 - 31	BIT6, BIT5, BIT4, BIT3, BIT2, BIT1	Control Input. See truth table and control voltage tables.	BIT1-6
32	Vss	Voltage supply.	
25	Vdd	Voltage supply.	
20	RF2	This port is DC coupled and matched to 50 Ohms.	——○ RF2
	GND	Exposed ground paddle must be connected to RF/DC ground	GND

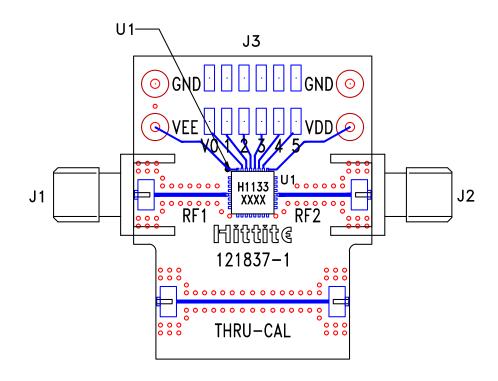
^{[2] 4-}Digit lot number XXXX



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Evaluation PCB



List of Materials for Evaluation PCB EV1HMC1133LP5 [1][3]

Item	Description	
J1 - J2	PCB Mount SMA RF Connector	
J3 - J4	Molex Header 2mm	
U1	HMC1133LP5 6-Bit Digital Phase Shifter	
PCB [2]	121837 Evaluation PCB	

- [1] Reference this number when ordering complete evaluation PCB
- [2] Circuit Board Material: Rogers 4350 or Arlon 25FR
- [3] Please refer to part's pin description and functional diagram for pin out assignments on evaluation board.

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Analog Devices upon request.